PCN Number:			20	0130	0312001				PCN Da	te:	03	/25/2013	
Titl	e:	A۱	/IC1200STD	UB	RQ′	l design - CMS	C1212071						
	stome ntact:		PCN_ww_ac	dmir	n_te	am@list.ti.com	Phone:	+1(214	1)48	0-6037	Dep	t:	Quality Services
Pro	pose	d 1	.st Ship Da	te:		09/25/2013	Estimate	ed Samp	ole .	Availabilit	y:	Up	on request
Cha	ange	Tyl	pe:			_				_			
Assembly Site			ly Site			Assembly Pro	cess			Assembly	Mate	eria	ls
	Desi	gn				Electrical Spec	cification			Design			
	Test	Sit	е			Packing/Shipp	oing/Label	ing/Labeling Test					
	Wafe	er E	Bump Site			Wafer Bump N	Material			Wafer Bu	mp S	np Site	
	Wafe	er F	ab Site			Wafer Fab Ma	terials			Wafer Fal	b Site		
						PCI	N Detail	S					
Des	script	ior	of Chang	e:									
The	die b	on	d pad open	ing	has	been increased	d and a cr	ack arre	st s	tructure ha	s bee	en a	idded.
Rea	Reason for Change:												
Alig	ın the	bo	nd pad ope	nin	g w	ith the manufac	cturing sta	ındard.					
Ant	ticipa	tec	l impact o	n F	it, I	Form, Function	n, Quality	or Rel	iabi	lity (posit	tive /	ne	egative):
Pos	Positive impact.												
Changes to product identification resulting from this PCN:													
Nor	None												
Product Affected:													
AM	AMC1200STDUBRQ1												

## **Qualification Data:**

This qualification has been specifically developed for the validation of this change. The qualification data validates that the proposed change meets the applicable released technical specifications.

## Automotive New Product Qualification Plan/Summary (As per AEC-Q100 and JEDEC Guidelines) Automotive New Product Qualification Plan/Summary (As per AEC-Q100 and JEDEC Guidelines)

Supplier Name:	Texas Instruments Inc.	Supplier Wafer Fabrication	Dallas, Texas, USA (TI DMOS 5
		Site/Process:	)/50HPA07ISO
			Taiwan (TSMC) /0.8DPDM
Supplier Code:		Supplier Die Rev:	Dual die – Die Rev "C" and Die Rev "F"
Supplier Part Number:	AMC1200STDUBRQ1	Supplier Assembly/Test Site:	Assembly - HNT , Thailand
			Final test - HNT, Thailand
Customer Name:	Catalog	Supplier Package/Pin:	DUB/8 (SOP)
Customer Part Number:		Pb Free Lead Frame (Y/N):	Y
Device Description:	Fully-Differential Isolation Amplifier	"Green" Mold Compound (Y/N):	Y
MSL Rating:	3	Operating Temp Range:	-40°C to +105°C
Peak Solder Reflow Temp:	260°C	Automotive Grade Level (1):	2
Prepared by Signature:	ItHong Tan	Date:	1/03//2013

Test	#	Reference	Test Conditions	Min Lots (2)	SS / lot (2)	Min Total (2)	Results Lot/pass/ fail	Generic Family Part / Comments	Exception s to AEC -Q100
			TEST GROUP A – ACCELERATED ENV	IDONMENT	CTDE	e teet	S (3)		
PC	A1	JESD22 A113 J-STD-020	Preconditioning; SMD only; Moisture Preconditioning for THB/HAST, AC/UHST, TC, HTSL, & HTOL	Performed devices, Pri TC & PTC	on <u>ALL</u> ior to TH	SMD	3 (3)		
THB or HAST	A2	JESD22 A101 JESD22 A110	Temperature Humidity Bias: 85°C/85% 1000 hours Highly Accelerated Stress Test: 130°C/85% 96 hours	3	77	231	3/231/0	MSPREL.12.AMC12 00.05002 MSPREL.12.AMC12 00.06003 MSPREL.12.AMC12 00.06004	
AC or UHST	A3	JESD22 A102 or JESD22 A118	Autoclave: 121C / 96 hours Unbiased Highly Accelerated Stress Test:	3	77	231	3/231/0	MSPREL.12.AMC12 00.05002 MSPREL.12.AMC12 00.06003 MSPREL.12.AMC12 00.06004	
TC	A4	JESD22 A104	Temperature Cycle: -65°C/+150°C/500 cycles  Post Temp Cycle Bond Pull 3 grams minimum ( 30 bonds Total)	3	77	231	3/231/0	MSPREL.12.AMC12 00.05002 MSPREL.12.AMC12 00.06003 MSPREL.12.AMC12 00.06004	
PTC	A5	JESD22-A105	Power Temperature Cycle: -40°C to +125°C for 1000 cycles	1	45	45	NA	NA	
HTSL	A6	JESD22 A103	High Temperature Storage Life: 175°C/500 hours	1	45	45	1/45/0	MSPREL.12.AMC12 00.05002	
			TEST GROUP B - ACCELERATED LIFE					-	
HTOL	B1	JESD22 A108	High Temp Operating Life: 150°C/408 hours	3	77	231	3/231/0	MSPREL.12.AMC12 00.05002 MSPREL.12.AMC12 00.06003 MSPREL.12.AMC12 00.06004 HPA07ISO process QBS MSPREL.10.ISO7421 .01001 MSPREL.09.ISO7421 .11015 MSPREL.09.ISO7420 .11002	

ELFR	B2	AEC-Q100- 008	Early Life Failure Rate: 125°C/48hours	3	800	2400	3/2400/0	MSPREL.12.AMC12 00.05002 MSPREL.12.AMC12 00.06003 MSPREL.12.AMC12 00.06004 HPA07ISO process QBS MSPREL.10.ISO7421 .02002 MSPREL.09.ISO7421 .11015 MSPREL.09.ISO7420 .11002	
NVM Enduran ce, Data Retentio n, and Operati onal Life	В3	AEC Q100- 005	NVM Endurance, Data Retention, and Operational Life	3	77	231		N/A	
Life		I.	TEST GROUP C – PACKAGE ASSEM	BLY INTEG	RITY 1	ESTS (3	)	<u>I</u>	
WBS	C1	AEC-Q100- 001	Wire Bond Shear Test: (Ppk > 1.67 and Cpk > 1.33)	30 bonds	5 parts Min.	30 bonds	1/80/0	Assembly MQ	
WBP	C2	Mil-Std-883 Method 2011	Wire Bond Pull: Each bonder used (Ppk > 1.67 and Cpk > 1.33)	30 bonds	5 parts Min.	30 bonds	1/80/ 0	Assembly MQ	
SD	C3	JESD22 B102	Solderability: (>95% coverage) 8 hr steam age	1	15	15	1/22/0 Pb 1/22/0 Pb Free	MSPREL.12.AMC12 00.06005	
PD	C4	JESD22 B100, JESD22 B108	Physical Dimensions: (Ppk > 1.67 and Cpk > 1.33)	3	10	30	3/30/0	PD1 PD2 and PD3	
SBS	C5	AEC-Q100- 010	Solder Ball Shear: (Ppk > 1.67 and Cpk > 1.33)	50 balls	3	50		N/A to non-solder ball surface mount devices	
LI	C6	JESD22 B105 Not Required for SMT parts	Lead Integrity: (No lead cracking or breaking)	50 leads	1	50		N/A to non-solder ball surface mount devices	

## TEST GROUP D - DIE FABRICATION RELIABILITY TESTS

Test	#	Reference	Test Conditions	Min Lots (2)	SS / lot (2)	Min Total (2)	Results Lot/pass/ fail	Generic Family Part / Comments	Exception s to AEC - Q100
EM	D1	JESD61	Electromigration: (Only if de-rating required beyond design rules)	-	-	-		Data available	
TDDB	D2	JESD35	Time Dependant Dielectric Breakdown:	-	-	-		N/A	
HCI	D3	JESD60 & 28	Hot Injection Carrier	-	-	-		N/A	
			TEST GROUP E- ELECTRICA	L VERIFIC	CATION		l .	<u> </u>	
TEST	E1	User/Supplier Specification	Pre and Post Stress Electrical Test.	All	All	All		100% of qualification devices	
НВМ	E2	AEC-Q100- 002	Electrostatic Discharge, Human Body Model	1	3	3	500V 3/0 1000V 3/0 1500V 3/0 2000V 3/0	MSPREL.12.AMC1 200.06006	
CDM	E3	AEC-Q100- 011	Electrostatic Discharge, Charged Device Model; (750V corner leads, 500V for all other leads)	1	3	3	250V 3/0 500V 3/0 750V 3/0	MSPREL.12.AMC1 200.06006	
LU	E4	AEC-Q100- 004	Latch-Up:	1	6	6	1/6/0	MSPREL.12.AMC1 200.06006	
ED	E5	AEC-Q100- 009	$\label{eq:continuous} \begin{tabular}{ll} Electrical Distributions: \\ (Test across recommended operating temperature range) \\ (Cpk > 1.67 \ , Ppk > 1.67) \\ \end{tabular}$	3	30	90	3/90/0 -40°C, 25°C, 125°C	To be performed by MSA	

(1)	Grade 0 (or A):	-40°C to +150°C ambient operating temperature range
	Grade 1 (or Q):	-40°C to +125°C ambient operating temperature range
	Grade 2 (or T):	-40°C to +105°C ambient operating temperature range
	Grade 3 (or I):	-40°C to +85°C ambient operating temperature range
	Grade 4 (or C):	-0°C to +150°C ambient operating temperature range

- (2) These are recommended minimum lot/sample sizes. Lot/sample size may be reduced depending on available data.
- (3) Generic data may be used.

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Reliability data shows characteristic failure mechanisms of the specific environmental stress as documented in the industry standards for each stress condition.

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